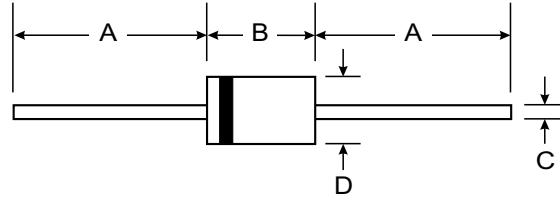


Features

- High switching speed: max. 4 ns
- Reverse voltage: max. 25V , 50V
- Peak reverse voltage: max. 35V, 75 V
- Pb / RoHS Free



Mechanical Data

- **Case:** DO-35 Glass Case
- **Weight:** approx. 0.13g

DO-35		
Dim	Min	Max
A	25.40	—
B	—	4.00
C	—	0.60
D	—	2.00
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

Parameter	Symbol	Value	Unit			
Maximum Peak Reverse Voltage	BAW75	25	V			
	BAW76	50				
Maximum Reverse Voltage	BAW75	35	V			
	BAW76	75				
Maximum Average Forward Current Half Wave Rectification with Resistive Load , f ≥ 50Hz	I _{F(AV)}	150 ⁽¹⁾	mA			
Maximum Power Dissipation	P _D	500 ⁽¹⁾	mW			
Maximum Surge Forward Current at t < 1μs , T _J = 25 °C	I _{FSM}	2	A			
Maximum Junction Temperature	T _J	200	°C			
Storage Temperature Range	T _S	-65 to + 200	°C			
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Current	I _R	V _R = 25 V	-	-	100	nA
		V _R = 50 V	-	-	100	
Forward Voltage	V _F	I _F = 30 mA	-	-	1.0	V
		I _F = 100 mA	-	-	1.0	
Reverse Breakdown Voltage	V _{(BR)R}	Test with 5μA pulses	35	-	-	V
			75	-	-	
Diode Capacitance	C _d	f = 1MHz ; V _R = 0	-	-	4.0	pF
			-	-	2.0	
Reverse Recovery Time	T _{rr}	I _F = 10 mA , I _R = 10 mA I _{rr} = 1mA	-	-	4	ns

Note : (1) Valid provided that leads are kept at ambient temperature at a distance of 8mm from case.

**FIG. 1 ADMISSIBLE POWER DISSIPATION
VERSUS AMBIENT TEMPERATURE**

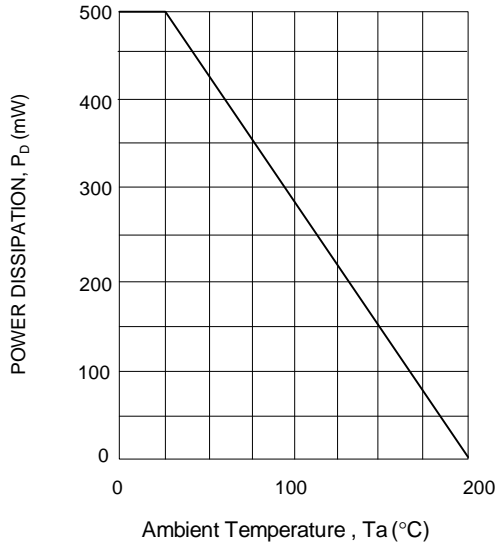
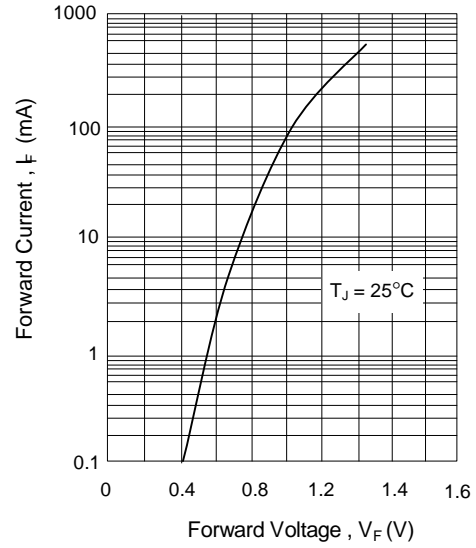
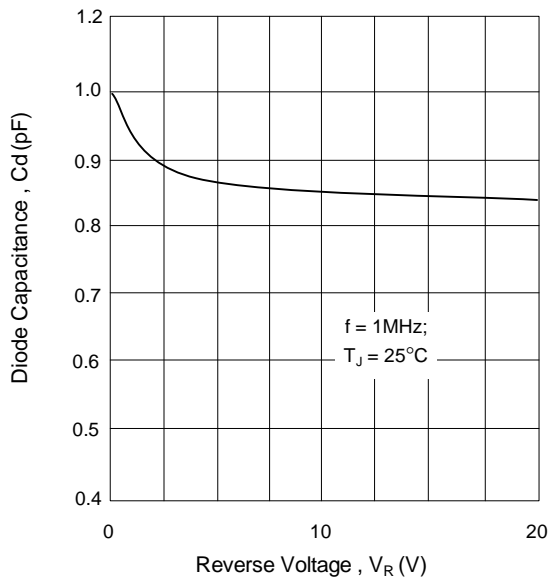


FIG. 2 TYPICAL FORWARD VOLTAGE



**FIG. 3 TYPICAL DIODE CAPACITANCE AS
A FUNCTION OF REVERSE VOLTAGE**



**FIG. 4 TYPICAL REVERSE CURRENT
VERSUS JUNCTION TEMPERATURE**

